Monolithic Amplifier

TSS-13LN+

 50Ω 1MHz to 1 GHz

CASE STYLE: DQ1225

The Big Deal

- Ultra-High IP3, +39.2 dBm typ.
- Low supply voltage, 3 to 5V
- Excellent Noise Figure, 1.1 dB typ.
- Shutdown feature

Product Overview

TSS-13LN+ (RoHS compliant) is an advanced wideband amplifier with shutdown feature. It is fabricated using E-PHEMT technology and offers extremely high dynamic range over a broad frequency range and with low noise figure. In addition, the TSS-13LN+ has good input and output return loss over a broad frequency range. TSS-13LN+ is enclosed in a 3mm x 3mm, 12-lead MCLP package and has very good thermal performance.

Key Features

| Feature | Advantages |
|--|---|
| Broad Band: 1MHz to 1GHz | Broadband covering primary wireless communications bands: VHF, UHF, Cellular |
| Extremely High IP3 38.4 dBm typical at 1 MHz 39.2 dBm typical at 0.5 GHz | The TSS-13LN+ matches industry leading IP3 performance relative to device size and power consumption. The combination of the design and E-PHEMT Structure provides enhanced linearity over a broad frequency range as evidence in the IP3 being approximately 11-18 dB above the P1dB point. This feature makes this amplifier ideal for use in: • Driver amplifiers for complex waveform up converter paths • Drivers in linearized transmit systems • Secondary amplifiers in ultra-High Dynamic range receivers |
| Shutdown feature | Allow users to turn on and off the amplifier with pulsed signals while keeping the power supply at constant voltage to minimize DC power consumption |
| Low Noise Figure 1.1 dB at 0.5 GHz | Enables lower system noise figure performance and along with High OIP3 provides high dynamic range |
| Low Supply Voltage | TSS-13LN+ supports low supply voltage operation which indicate low power consumption. |

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Product Features

- High IP3, 39.2 dBm typ. at 0.5 GHz
- Gain, 22.8 dB typ. at 0.5 GHz
- Low noise figure, 1.1 dB at 0.5 GHz
- Low voltage, 5V and 3V
- Shutdown feature

Typical Applications

- Base station infrastructure
- CATV
- Cellular



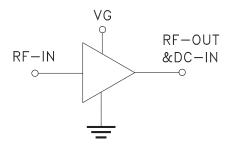
+RoHS Compliant

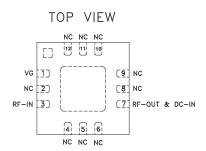
The +Suffix identifies RoHS Compliance. See our web site for RoHS Compliance methodologies and qualifications

General Description

TSS-13LN+ (RoHS compliant) is an advanced wideband amplifier with shutdown feature. It is fabricated using E-PHEMT technology and offers extremely high dynamic range over a broad frequency range and with low noise figure. In addition, the TSS-13LN+ has good input and output return loss over a broad frequency range. TSS-13LN+ is enclosed in a 3mm x 3mm, 12-lead MCLP package and has very good thermal performance.

simplified schematic and pad description





| Function | Pin Number | Description |
|------------------|--------------|------------------------------------|
| RF IN | 3 | RF Input |
| RF-OUT and DC-IN | 7 | RF Output and DC Bias |
| GND | Paddle | Connections to ground. |
| NC | 2, 4-6, 8-12 | No connection, grounded externally |
| VG | 1 | Control voltage for shutdown (VG) |

Electrical Specifications¹ at 25°C & 50Ω, unless noted

| Parameter | Condition (MHz) | | | | Amplifier- OFF | Amplifier- ON VDD = 3V | Amplifier- OFF VDD = 3V | Units |
|---|--------------------|------|-------|------|-------------------|------------------------------|-------------------------------|---------|
| | | | | | VDD = 5V | | | |
| | | Min. | Тур. | Max. | Тур. | Тур. | Тур. | |
| Frequency Range | | 1 | | 1000 | 1-1000 | 1-1000 | 1-1000 | MHz |
| | 1 | | 3.1 | | | 3.0 | | dB |
| | 20 | | 1.1 | | | 1.1 | | |
| Noise Figure | 250 | | 1.1 | | | 1.1 | | |
| | 500 | | 1.1 | | | 1.1 | | |
| | 1000 | | 1.2 | | | 1.3 | | |
| | 1 | 22.1 | 24.7 | 27.1 | -24 | 23.9 | -24 | dB |
| | 20 | _ | 24.2 | _ | -22 | 23.5 | -22 | |
| Gain | 250 | 20.6 | 23.0 | 25.2 | -21 | 22.3 | -21 | |
| | 500 | _ | 22.8 | _ | -22 | 21.9 | -22 | |
| | 1000 | 18.2 | 20.9 | 22.2 | -27 | 19.5 | -27 | |
| Reversed Isolation | 1-1000 | | 26 | | 27 | 26 | 27 | dB |
| | 1 | | 11 | | 12 | 10 | 12 | dB |
| | 20 | | 15 | | 12 | 15 | 12 | |
| Input Return Loss | 250 | | 18 | | 12 | 19 | 12 | |
| | 500 | | 21 | | 12 | 17 | 12 | |
| | 1000 | | 14 | | 10 | 10 | 10 | |
| | 1 | | 11 | | 1 | 11 | 1 | dB |
| | 20 | | 19 | | 2 | 21 | 2 | |
| Output Return Loss | 250 | | 18 | | 2 | 21 | 2 | |
| | 500 | | 25 | | 2 | 21 | 2 | |
| | 1000 | | 11 | | 2 | 10 | 2 | |
| | 1 | | 20.3 | | | 14.2 | | dBm |
| | 20 | | 22.4 | | | 16.3 | | |
| Output Power @1dB compression AMP-ON | 250 | | 24.1 | | | 19.3 | | |
| | 500 | | 24.5 | | | 19.5 | | |
| | 1000 | | 23.4 | | | 18.3 | | |
| | 1 | _ | 38.4 | | | 31.6 | | dBm |
| | 20 | _ | 40.3 | | | 33.2 | | |
| Output IP3 (Pout = 0dBm/Tone) | 250 | _ | 39.6 | | | 34.4 | | |
| | 500 | 35.4 | 39.2 | | | 33 | | |
| | 1000 | - | 36.2 | | | 29.4 | | |
| Device Operating Voltage (VDD) | 1000 | 4.75 | 5 | 5.25 | 5 | 3 | 3 | V |
| Device Operating Voltage (VDD) Device Operating Current (ID) | | 7.73 | 142 | 151 | 5 | 72 | 3 | mA |
| Control Voltage (VG) | | | 0 | 131 | 5 | 0 | 5 | V |
| DC Current (ID) Variation Vs. Temperature ² | | | 10 | | 3 | 33 | 3 | uA/degC |
| DC Current(ID) Variation Vs. Voltage | | | 0.025 | | | 0.033 | | mA/mV |

^{1.} Measured on Mini-Circuits Characterization test board TB-TSS-13LN+. See Characterization Test Circuit (Fig. 1) 2. (Current at 105° C — Current at -45° C)/150

Absolute Maximum Ratings³

| Parameter | Ratings | | |
|---|---|--|--|
| Operating Temperature (ground lead) | -40°C to 105°C | | |
| Storage Temperature | -65°C to 150°C | | |
| Total Power Dissipation | 3.3W | | |
| Input Power | 28 dBm (5 minutes max.) 6 dBm (continuos) for 1- 30 MHz 10 dBm (continuos) for 0.03-1 GHz | | |
| DC Voltage V _{DD} ⁴ (Pad 7) | 10V | | |
| DC Voltage V _G ⁵ (Pad 1) | 10V | | |

 $^{^3}$ Permanent damage may occur if these limits are exceeded. 4 Measured by keeping V₆=0V. 5 Measured by keeping V₆0=5V.

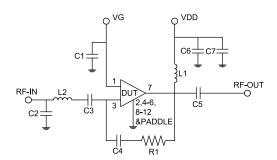
Control Voltage (V_G) Fig. 1

| | Min. | Тур. | Max. | Units |
|---------------|------|------|------|-------|
| Amplifier-ON | _ | 0 | 0.7 | V |
| Amplifier-OFF | 1.9 | 5 | _ | V |

Switching Specifications

| Parameter | | | 3V Typ. | Units |
|--------------------------|----------------------------------|------|------------|-------|
| Amplifian ON to Chutdour | OFF TIME (50% Control to 10% RF) | | 6.2 | |
| Amplifier ON to Shutdown | FALL TIME (90 to 10% RF) 7.4 | | 3.6 | μS |
| A life Objet A ON | ON TIME (50% Control to 90% RF) | 95.2 | 144.7 | _ |
| Amplifier Shutdown to ON | ISE TIME (10% to 90% RF) 60.0 | | 200.7 | μS |
| Control Voltage Leakage | | | 311.0 | mV |

Characterization Test Circuit / Recommended Application Circuit



| Component | Size | Value | Part Number | Manufacturer |
|-----------|------|---------|--------------------|--------------|
| C1 | 0402 | 0.1uF | GRM155R71C104KA88D | Murata |
| C2 | 0402 | 1.5pF | GRM1555C1H1R5CA1D | Murata |
| C3 | 0603 | 2.2uF | GRM188C71E225KE11D | Murata |
| C4 | 0402 | 0.1uF | GRM155R71C104KA88D | Murata |
| C5 | 0603 | 2.2uF | GRM188C71E225KE11D | Murata |
| C6 | 0402 | 1000pF | GRM1555C1H102JA01D | Murata |
| C7 | 0805 | 10uF | GRM21BC71E106KE11L | Murata |
| L1 | 1210 | 15uH | LQH32DN150K53L | Murata |
| L2 | 0603 | 5.1nH | 0603CS-5N1XJLU | Coilcraft |
| R1 | 0402 | 1.5K0hm | RK73H1ETTP1501F | Koa |

Fig 1. Block diagram of Test Circuit used for characterization. (DUT soldered on Mini-Circuits Characterization test board TB-TSS-13LN+) Gain, Return loss, Output power at 1dB compression (P1dB), output IP3 (OIP3) and noise figure measured using Agilent's N5242A PNA-X microwave network analyzer.

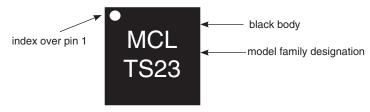
Conditions:

- 1. Gain and Return Loss: Pin= -25dBm
- 2. Output IP3 (OIP3): Two tones, spaced 1 MHz apart, +0dBm/tone at output.
- 3. Switching Time

RF Signal: Pin=-25 dBm, f_{RF}=500 MHz.

 V_{DD} =3 & 5V DC, V_{G} =Pulse signal at 1 KHz with V_{HIGH} =5V, V_{LOW} =0V, 50% duty cycle.

Product Marking

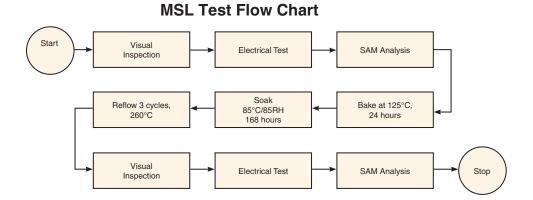


Marking may contain other features or characters for internal lot control

| Additional Detailed Technical Information additional information is available on our dash board. To access this information click here | | | | |
|--|---|--|--|--|
| | Data Table | | | |
| Performance Data | Swept Graphs | | | |
| | S-Parameter (S2P Files) Data Set (.zip file) | | | |
| Case Style | DQ1225 Plastic package, exposed paddle lead finish: Matte-Tin | | | |
| Tape & Reel | F66 | | | |
| Standard quantities available on reel | 7" reels with 20, 50, 100, 200, 500 or 1K devices | | | |
| Suggested Layout for PCB Design | PL-623 | | | |
| Evaluation Board | TB-TSS-13LN+ | | | |
| Environmental Ratings | ENV08T9 | | | |

ESD Rating

Human Body Model (HBM): Class 1A (Pass 250 V) in accordance with ANSI/ESD STM 5.1 - 2001



Additional Notes

- A. Performance and quality attributes and conditions not expressly stated in this specification document are intended to be excluded and do not form a part of this specification document.
- B. Electrical specifications and performance data contained in this specification document are based on Mini-Circuit's applicable established test performance criteria and measurement instructions.
- C. The parts covered by this specification document are subject to Mini-Circuits standard limited warranty and terms and conditions (collectively, "Standard Terms");
 Purchasers of this part are entitled to the rights and benefits contained therein. For a full statement of the Standard Terms and the exclusive rights and remedies thereunder, please visit Mini-Circuits' website at www.minicircuits.com/MCLStore/terms.jsp

